B & BS Package High Temperature Stacked Array





The Summit[™] NL-QD-Q1yzz-B package (up to 10 bars) and NL-QD-Q1yzz-BS package (up to 19 bars) are conductively cooled stacked diode laser arrays designed to operate at very high temperatures. These stacks are built with diode bars of 60W QCW to 200W QCW.

These diode laser bar arrays benefit from a fully mastered technology and are designed to offer the highest efficiency and most reliable operation at very high junction temperatures.

The packaging has been optimized to reduce the overall thermal resistance. NL-QD-Q1yzz-B and NL-QD-Q1yzz-BS stacks are ideal for applications under severe environmental conditions, such as pumping solid-state lasers for designators and illuminators. These compact and rugged designs are well suited to defense and space applications requiring small footprint and high reliability.

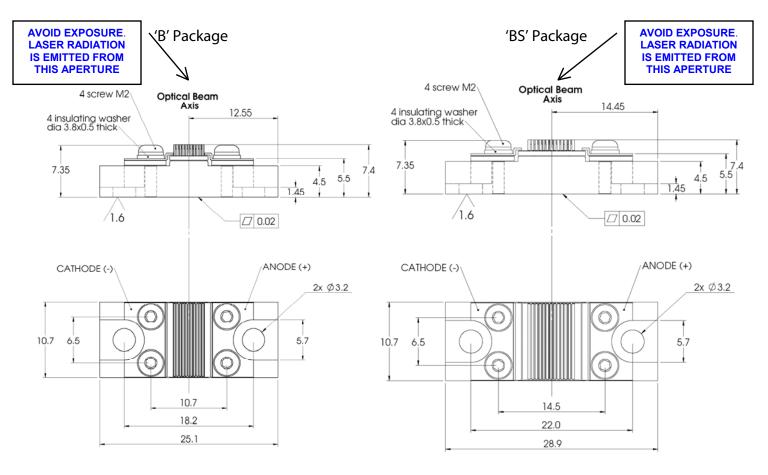
Features

- Highest Efficiency
- Highest Temperature Endurance
- Shock and Vibration Rugged
- Tested for Space Applications
- Low Thermal Resistance
- Case Temperature up to 75°C

Applications

- Target Designation
- Ranging
- LIDAR
- Space Environments
- Multi-Spectral Imaging
- Medical
- Ignition
- Mapping

Package Dimensions



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Case temperature: + 60° C

Quasi-continuous mode:

pulse width = 200μs repetition rate = up to 100Hz

Device Specifications		UNITS	NL-QD-Q1yzz-B		NL-QD-Q1yzz-BS
Parameters					
Number of diode bars			zz = 2 to 10		zz = 10 to 19
Pitch between diode bars		μm	400		400
Emitting area		mm x mm	10 x 3.6 (10 bars)		10 x 7.2 (19 bars)
			y = 2	y = 3	y = 4
QCW Optical Power per Diode Bar		Watt	60	80	100
Threshold current		Amp.	19	19	19
Operating current	Тур.	Amp.	70	88	105
	Max.	Amp.	75	97	120
Operating voltage		Volt	< 2 / bar		< 2 / bar
Total efficiency	Тур.	%	48		48
٨		%	42		42
Beam divergence (FWHM)		degree	10 x 40		10 x 40

Note:

Variation of wavelength is approximately 0.26 to 0.3 nm/°C.

Standard wavelength is 808nm.

Spectral width is \leq 4 nm FWHM.

Tolerance on wavelength is +/- 3nm.

Other wavelength selections are available.

Possibility of pitch between diode bars of 500µm.

Specifications are for nominal lifetime 5. 108 pulses (for 200µs pulse width).

Operating at higher power or higher temperature will accelerate component aging, increase threshold current, and decrease slope efficiency.

CFR Regulation

These components do not comply with the federal regulation (Title 21 CFR Chapter 1 Subchapter J) as administered by the Center for Device and Radiological Health. Purchaser acknowledges that their products must comply with these regulations before they can be sold to an end-user.



Notice

nLight continually improves its products to provide our customers with outstanding quality and reliability. *n*LIGHT may make changes to specifications and product descriptions at any time, without notice. In addition, *n*LIGHT offers a limited warranty to ensure customer satisfaction. For complete details, please check with your *n*LIGHT sales representative.



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